

Green Products

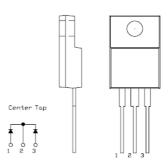
SBRF20150CT SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

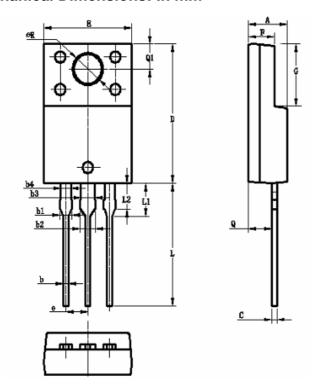
Features:

- 200°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



OUTLINE DRAWING

Mechanical Dimensions: In mm



	OPTION 1(CJ)		OPTION	OPTION 2(HD)	
Dim	Min	Max	Min	Max	
Α	4.4	4.6	4.30	4.70	
b	0.6T	ΥP	0.50	0.75	
b1	1.3T	ΥP	1.30	1.40	
b2	1.7T	ΥP	1.70	1.80	
b3	1.6T	ΥP	1.50	1.75	
b4	1.2T	ΥP	1.10	1.35	
С	0.60	ГҮР	0.50	0.75	
D	14.8	15.1	14.80	15.20	
Е	10.06	10.26	9.96	10.36	
е	2.55TYP		2.54TYP		
F	2.9	3.1	2.80	3.20	
G	6.5	6.9	6.50	6.90	
L	12.7	13.7	12.8	13.2	
L1	3.4	3.8	3.60	4.00	
L2	2.6	3.0	-	-	
Q	2.5	2.9	2.50	2.90	
Q1	2.5	2.9	2.70	REF	
ØR	3.5REF		3.50REF		

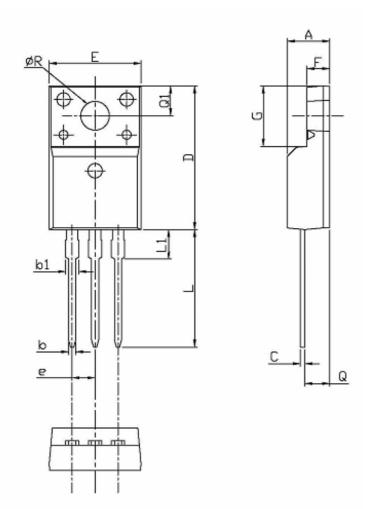
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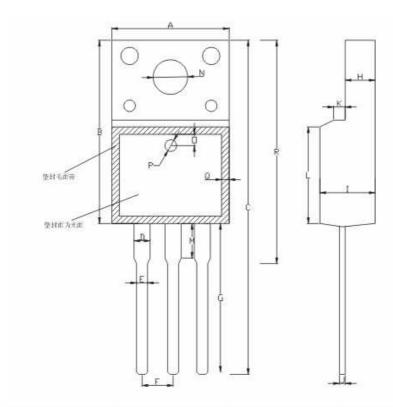


	OPTION 3		OPTION 4		
Dim	Min	Max	Min	Max	
Α	4.53	4.93	4.50	4.90	
b	0.71	0.91	0.70	0.90	
b1	1.15	1.39	1.33	1.47	
С	0.36	0.53	0.45	0.60	
D	15.67	16.07	15.67	16.07	
E	9.96	10.36	9.96	10.36	
е	2.54TYP		2.54 BSC		
F	2.34	2.76	2.34	2.74	
G	6.50	6.90	6.48	6.88	
L	12.37	12.77	12.78	13.18	
L1	2.23	2.63	3.03	3.43	
Q	2.56	2.96	2.56	2.96	
Q1	3.10	3.50	3.10	3.50	
ØR	2.98	3.38	3.08	3.28	





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A:10.20	± 0.50	B:15.90	± 0.50	C:29.00	± 1.00	D:1.24	± 0.10
E:0.80	± 0.10	F:2.54	± 0.10	G:13.10	$\pm 1,0$	H:2.55	± 0.05
I:4.70	±0.05	J:0.50	± 0.05	K:1.20	±0.20	L:8.00	± 0.50
M:3.00	± 0.50	N:3.20	± 0.20	O:1,25	±0.05	P:1.5	± 0.05
Q:1.0	±0.20	R:19.2	±1.0				

OPTION 5 (SR)

ITO-220AB





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Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0 Where XXXXX is YYWWL

SBR = Device Type F = Package type

20 = Forward Current (20A) 150 = Reverse Voltage (150V)

CT = Configuration

SSG = SSG YY = Year WW = Week L = Lot Number

Ordering Information:

Device	Package	Shipping
SBRF20150CT	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	150	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =133℃, rectangular wave form	10(Per leg) 20(Per device)	Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	150	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 10A, Pulse, T _J = 25 °C	0.93	V
(per leg)*	V _{F2}	@ 10A, Pulse, T _J = 125 °C	0.78	V
Max. Reverse Current at DC condition (per leg)	I _R	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}C$	1.0	mA
Repetitive peak reverse current	IRRM	tp = 2 μs square F= 1 kHz	1	А
Non-Repetitive Avalanche Energy	Eas	T _J = 25 °C, I _{AS} = 2A, L = 1mH	2	mJ
Max. Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz$	400	pF
Typical Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

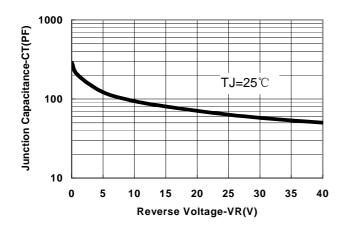
Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +200	°C
Max. Storage Temperature	T_{stg}	-	-55 to +200	°C
Maximum Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		•

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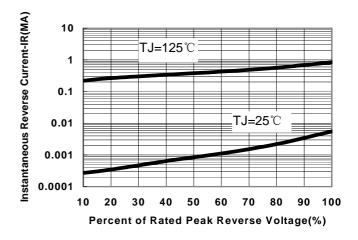


Fig.1-Typical Junction Capacitance Per Leg

Fig.2-Typical Reverse Leakage Characteristics Per Leg

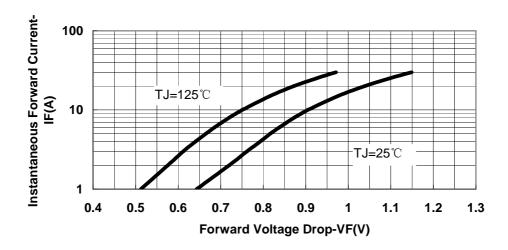


Fig.3-Typical Forward Characteristics

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Technical Data Data Sheet N0923, Rev. A

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